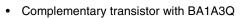


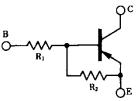
# COMPOUND TRANSISTOR BN1A3Q

# on-chip resistor PNP silicon epitaxial transistor For mid-speed switching

### FEATURES

On-chip bias resistor
 (R<sub>1</sub> = 1.0 kΩ, R<sub>2</sub> = 10 kΩ)





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PACKAGE DRAWING (UNIT: mm)

### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-60	V
Collector to emitter voltage	VCEO	-50	V
Emitter to base voltage	VEBO	-5	V
Collector current (DC)	IC(DC)	-100	mA
Collector current (Pulse)	IC(pulse) *	-200	mA
Total power dissipation	Рт	250	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

\* PW  $\leq$  10 ms, duty cycle  $\leq$  50 %

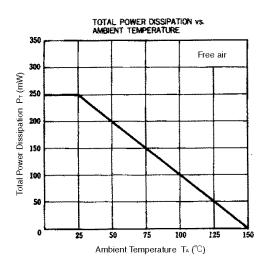
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

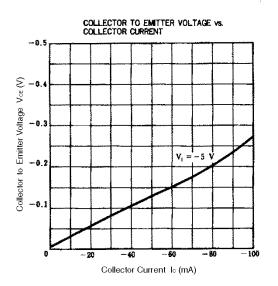
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -50 \text{ V}, \text{ I}_{E} = 0$			-100	nA
DC current gain	hfe1 **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	35	60	80	-
DC current gain	hfe2 **	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -50 \text{ mA}$	80	200		-
Collector saturation voltage	VCE(sat) **	$I_{C} = -5.0 \text{ mA}, I_{B} = -0.25 \text{ mA}$		-0.04	-0.2	V
Low level input voltage	VIL **	$V_{CE} = -5.0 \text{ V}, \text{ I}_{B} = -100 \ \mu\text{A}$		-0.7	-0.5	V
High level input voltage	ViH **	$V_{CE} = -0.2 \text{ V}, \text{ Ic} = -5.0 \text{ mA}$	-2.0	-1.0		V
Input resistance	R1		0.7	1.0	1.3	kΩ
E-to-B resistance	R2		7	10	13	kΩ
Turn-on time	ton	$V_{CC} = -5 V, R_{L} = 1 k\Omega$			0.2	μs
Storage time	tstg	$V_{I} = -5 V$ , PW = 2 $\mu$ s			5.0	μs
Turn-off time	toff	duty cycle≤2 %			6.0	μs

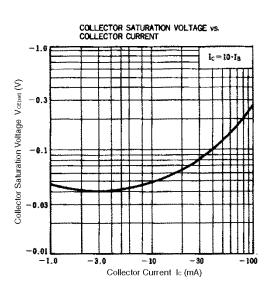
\*\* PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %

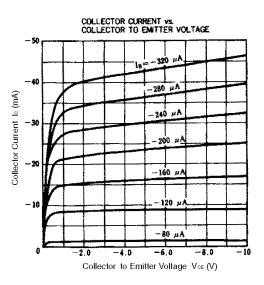
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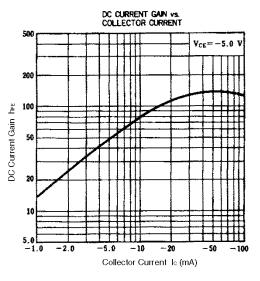
### TYPICAL CHARACTERISTICS (Ta = 25°C)



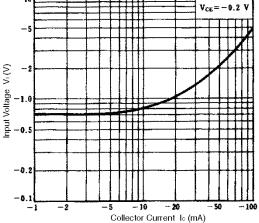






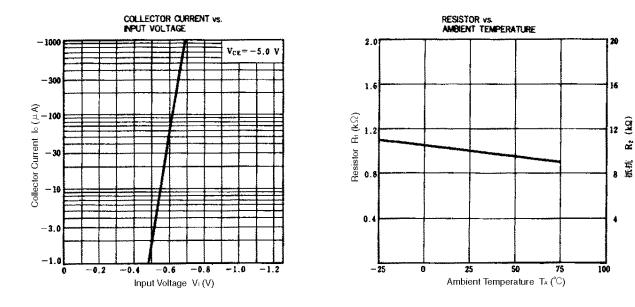


INPUT VOLTAGE vs. COLLECTOR CURRENT



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